# TVS Diodes Transient Voltage Suppression Diodes

**SPC1 Series** 



#### **Description**

The SPC1 in SMTO-218 package provide the enhanced quality, easy manufacturing than typical through-hole TVS components. They can be connected in series and/or parallel to create various capability and flexible protection solutions.

#### **Applications**

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

#### **Features**

- Bi-directional
- Low clamping and slope resistance
- For automatic pick and place assembly and reflow process to reduce the manufacturing cost and increase the soldering quality compared to axial leads package
- Patent pending package design
- Meet MSL level 1, per J-STD-020, LF Maximum peak of 245
   °C
- Pb-free E3 means 2<sup>nd</sup> level interconnect is Pb-free and the terminal finish material is tin (Sn)
- ESD follow IEC 61000-4-2
- Halogen free and RoHS compliant
- Tube or tape and reel pack options available

#### **Functional Diagram**



Bi-Directional

#### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted )

| Part Number | Voltage Reve   | Max.<br>Reverse                           | everse Voltage |              | Current        | Max. Clamping Voltage V <sub>CL</sub> @Peak Pulse Current (I <sub>PP</sub> ) |                              |                                | Max. Temp<br>Coefficient | Max.<br>Capacitance |
|-------------|----------------|---|----------------|--------------|----------------|--|------------------------------|--------------------------------|--------------------------|---------------------|
|             | V <sub>R</sub> | Leakage<br>I <sub>R</sub> @V <sub>R</sub> |                | l₁ Min<br>ax | I <sub>T</sub> | V <sub>CL</sub>  | I <sub>PP</sub><br>(8/20 μS) | Ι <sub>ΡΡ</sub><br>(10/350 μS) | of V <sub>BR</sub>       | 0 Bias 10KHz        |
|             |                |   | Min            | Max          |                |  | Min                          | Typical                        |                          |                     |
|             | (V)            | (μΑ)                                      | ('             | <b>V</b> )   | (uA)           | (V)  | (A)                          | (A)                            | (%/°C)                   | (nF)                |
| SPC1-380C   | 380            | 10  | 401            | 443          | 10             | 520  | 1000                         | 100                            | 0.1                      | 2.2                 |
| SPC1-430C   | 430            | 10  | 440            | 490          | 10             | 625  | 1000                         | 100                            | 0.1                      | 2.2                 |

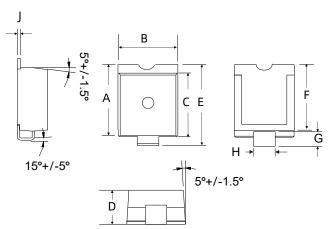
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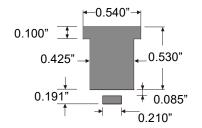


**Transient Voltage Suppression Diodes** 

#### **Package Outline Dimensions (SMTO-218)**



Note: Coplanarity of solder side is controlled within 0.10mm



Mounting Pad Layout (Inch)

| O      | Millim | eters | Inches |       |  |
|--------|--------|-------|--------|-------|--|
| Symbol | Min.   | Max.  | Min.   | Max.  |  |
| А      | 15.78  | 16.63 | 0.621  | 0.655 |  |
| В      | 13.43  | 15.09 | 0.529  | 0.594 |  |
| С      | 13.83  | 14.24 | 0.544  | 0.561 |  |
| D      | 6.94   | 7.24  | 0.273  | 0.285 |  |
| E      | 17.82  | 18.72 | 0.702  | 0.737 |  |
| F      | 14.40  | 14.76 | 0.567  | 0.581 |  |
| G      | 1.88   | 2.84  | 0.074  | 0.112 |  |
| Н      | 4.89   | 5.65  | 0.193  | 0.222 |  |
| J      | 0.72   | 0.85  | 0.028  | 0.033 |  |

#### **Maximum Ratings and Characteristics**

(Ratings at 25 °C ambient temperature unless otherwise specified.)

| Parameter                     | Symbol           | Value      | Unit |
|-------------------------------|------------------|------------|------|
| Storage Temperature Range     | T <sub>STG</sub> | -55 to 150 | °C   |
| Operating Junction            | TJ               | -55 to 125 | °C   |
| Current Rating (8/20 μS wave) | I <sub>PP</sub>  | 10         | kA   |

### **Physical Specifications**

| Weight   | Contact manufacturer                                      |
|----------|---|
| Case     | Epoxy molding compound encapsulated                       |
| Terminal | Tin plated lead, solderability per MIL-STD-202 Method 208 |





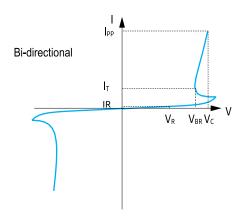
### TVS Diodes

**Transient Voltage Suppression Diodes** 

#### **Environmental Specifications**

| Temperature Cycling | JESD22-A104               |
|---------------------|---------------------------|
| HTRB                | JESD22-A108               |
| MSL                 | JESDEC-J-STD-020, Level 1 |
| H3TRB               | JESD22-A101               |
| RSH                 | JESD22-B106               |

#### **I-V Curve Characteristics**



P<sub>PPM</sub> - Peak Pulse Power Dissipation

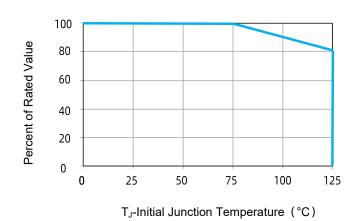
V<sub>R</sub> - Stand-off Voltage

V<sub>BR</sub> - Breakdown Voltage

V<sub>C</sub> - Clamping Voltage

I<sub>R</sub> - Reverse Leakage Current

#### Performance Curve for Reference(T<sub>A</sub>=25 °C unless otherwise noted)





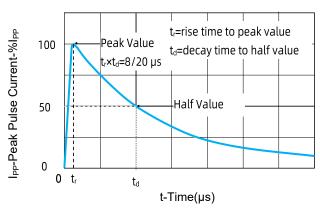
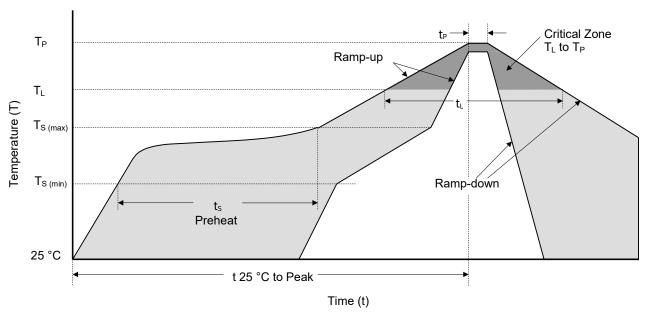


FIGURE 2 Pulse Waveform



### **Soldering Parameters**



**Reflowing Condition** 

| Reflow Solderi                         | Lead-Free Assembly                       |                    |  |
|--|--|--------------------|--|
|  | Temperature Min (T <sub>S (min)</sub> )  | 150 °C             |  |
| Pre-heat                               | Temperature Max (T <sub>S (max)</sub> )  | 200 °C             |  |
|  | Time (min to max) (t₅)                   | 60 ~ 120 seconds   |  |
| Average Ramp Up Rate (L                | iquidus Temp (TL) to Peak                | 3 °C / second max. |  |
| T <sub>S</sub> (max) to T <sub>L</sub> | Ramp-up Rate                             | 3 °C / second max. |  |
| D 4                                    | Temperature (T <sub>L</sub> ) (Liquidus) | 217 °C             |  |
| Reflow                                 | Time (min to max) (t <sub>L</sub> )      | 60 ~ 150 seconds   |  |
| Peak Temp                              | 260 <sup>+0/-5</sup> °C                  |                    |  |
| Time of within 5 °C of Act             | 20 ~ 40 seconds                          |                    |  |
| Ramp-do                                | 6 °C / second max.                       |                    |  |
| Time from 25 °C to                     | 8 Minutes max.                           |                    |  |
| Do Not                                 | 260 °C                                   |                    |  |

### **Wave Soldering (Solder Dipping)**

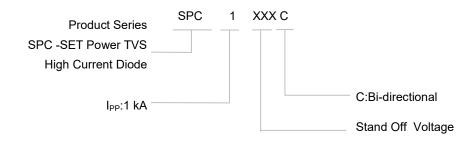
| Peak Temperature | 260 °C+0 /- 5 °C |
|------------------|------------------|
| Dipping Time     | 10 seconds       |
| Soldering Number | 1 time           |



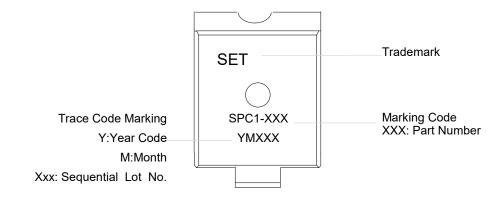


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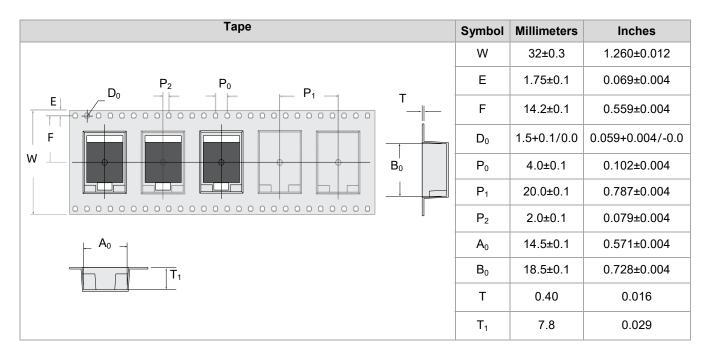
#### **Part Numbering System**



#### **Marking**



#### **Packaging Information**



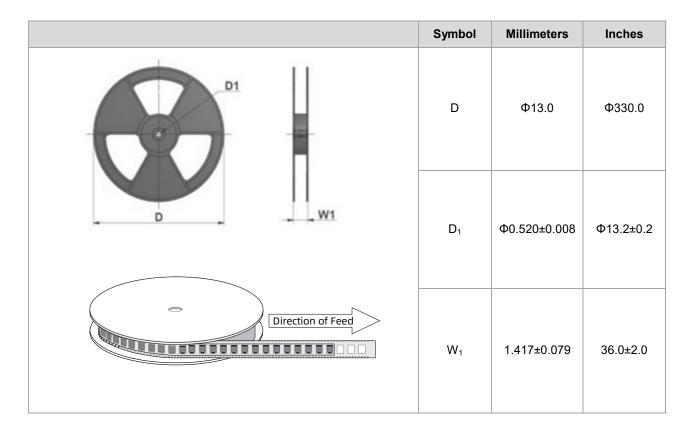


**SPC1 Series** 

### **TVS Diodes**

**Transient Voltage Suppression Diodes** 

### **Packaging Information**



| Part Number | Weight | Packaging Option             | QTY's   |
|-------------|--------|------------------------------|---------|
| SPC1-XXXXC  | 4.33 g | Tape & Reel – 32 mm/13" tape | 400 PCS |



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#### **Glossary**

| Item   | Description  |
|--|--|
| V <sub>C</sub>                                       | Clamping Voltage  Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.  |
| V <sub>WM</sub> (V <sub>R</sub> ) (V <sub>SO</sub> ) | Rated Working Standoff Voltage  Maximum-rated value of dc or repetitive peak positive cathode-to-anode voltage that may be continuously applied to TVS over the standard operating temperature range.                |
| / <sub>D</sub> (I <sub>R</sub> )                     | Standby Current Current through TVS at rated stand-off voltage.  |
| <b>V</b> BR  | Breakdown Voltage Voltage across TVS at a specified current $I_T$ in the breakdown region.   |
| I <sub>PPM</sub>                                     | Rated Random Recurring Peak Impulse Current  Maximum-rated value of random recurring peak impulse current that may be applied to a device.   |
| P <sub>M(AV)</sub>                                   | Rated Average Power Dissipation  Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.                                |
| P <sub>PPM</sub>                                     | Rated Random Recurring Peak Impulse Power Dissipation  Maximum-rated value of the product of rated random recurring peak impulse current ( $I_{PPM}$ ) multiplies by specified maximum clamping voltage ( $V_{C}$ ). |
| C <sub>J</sub>                                       | Capacitance Capacitance across the TVS measured at a specified frequency and voltage.  |
| V <sub>FS</sub><br>(V <sub>F</sub> )                 | Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current ( $I_{FS}$ ) and time duration.  |
| / <sub>FS</sub>                                      | Forward Surge Current Pulsed current through TVS in the forward conducting region.   |
| α <sub>V(BR)</sub>                                   | Temperature Coefficient of Breakdown Voltage  The change of breakdown voltage divided by the change of temperature.  |
| I <sub>PP</sub>                                      | Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.  |

--(GB-T 18802.321 / IEC 61643-321 / JESD210A)

## **TVS Diodes**

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#### Usage

- 1.TVS must be operated in the specified ambient temp.
- 2.Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

#### Replacement

- 1.If TVS is visually damaged, please replace it.
- 2.TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

#### Storage

- 1.Storage Temp. Range: (-55 to 150) °C.
- 2.Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

#### **Environmental Conditions**

- 1.TVS should not be exposed to the open air, nor direct sunshine.
- 2.TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- 3.TVS should avoid sand dust, salt mist, or other harmful gases.

#### Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

#### **Installation Mechanical Stress**

- 1.Do not knock TVS when installing, to avoid mechanical damage.
- 2.Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.